



2SA2127

Bipolar Transistor -50V, -2A, Low VCE(sat), PNP Single MP

ON Semiconductor®

<http://onsemi.com>

Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment

Features

- Adoption of MBIT process
- High current capacity and wide ASO
- Low saturation voltage

Specifications

Absolute Maximum Ratings at Ta=25°C

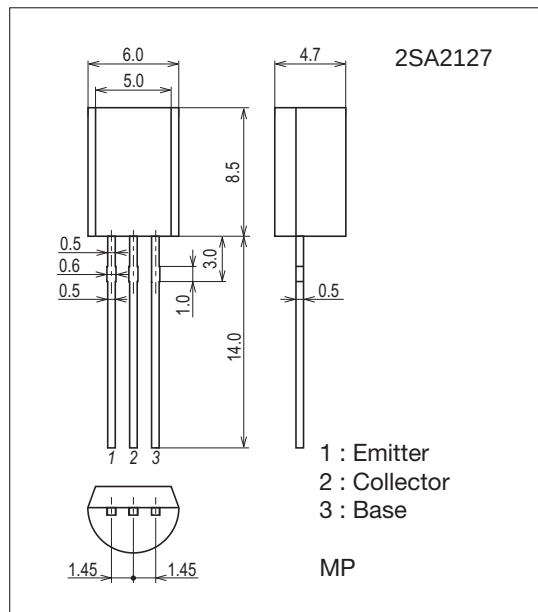
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		-50	V
Collector-to-Emitter Voltage	V _{CE0}		-50	V
Emitter-to-Base Voltage	V _{EB0}		-6	V
Collector Current	I _C		-2	A
Collector Current (Pulse)	I _{CP}		-4	A
Base Current	I _B		-400	mA
Collector Dissipation	P _C		1	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

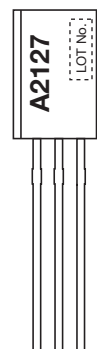
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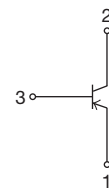
Product & Package Information

- Package : MP
- JEITA, JEDEC : SC-51, TO-92(1-WATT), TO-226AE
- Minimum Packing Quantity : 1,000 pcs./box

Marking



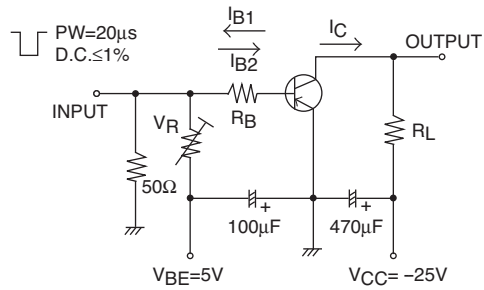
Electrical Connection



Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = -40\text{V}, I_E = 0\text{A}$			-1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -4\text{V}, I_C = 0\text{A}$			-1	μA
DC Current Gain	h_{FE1}	$V_{CE} = -2\text{V}, I_C = -100\text{mA}$	200		560	
	h_{FE2}	$V_{CE} = -2\text{V}, I_C = -1.5\text{A}$	40			
Gain-Bandwidth Product	f_T	$V_{CE} = -10\text{V}, I_C = -300\text{mA}$		420		MHz
Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, f = 1\text{MHz}$		16		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -1\text{A}, I_B = -50\text{mA}$		-0.2	-0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -1\text{A}, I_B = -50\text{mA}$		-0.9	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, I_E = 0\text{A}$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1\text{mA}, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0\text{A}$	-6			V
Turn-On Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}			250		ns
Fall Time	t_f			24		ns

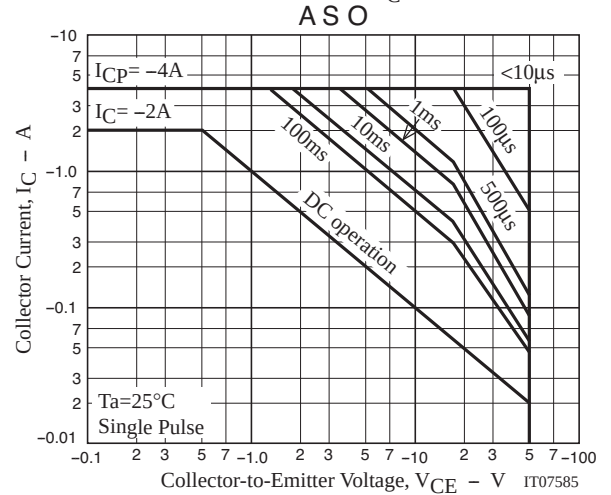
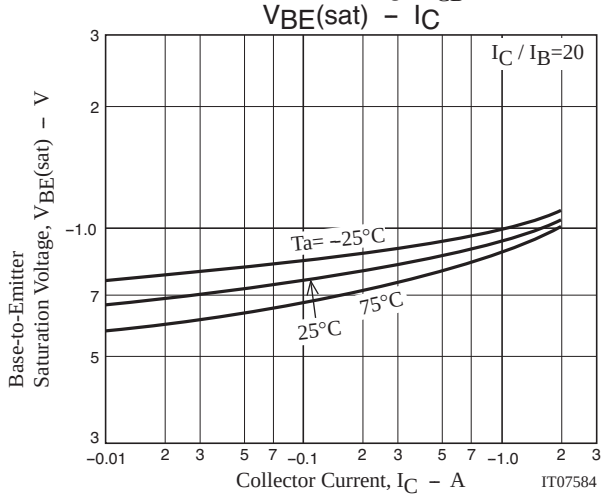
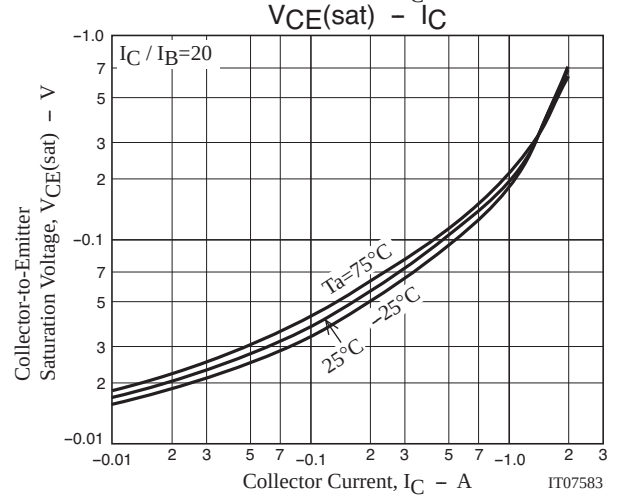
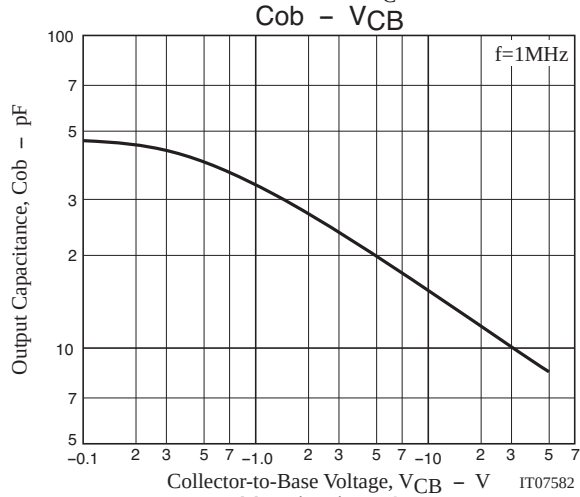
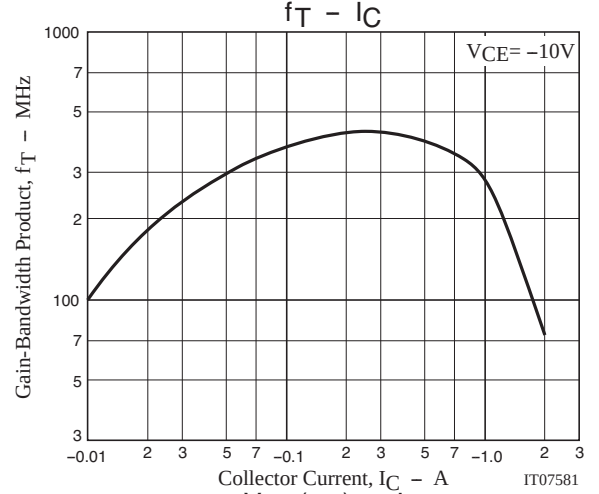
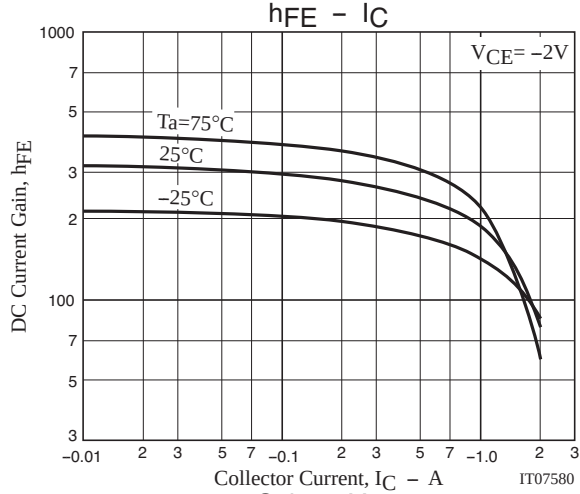
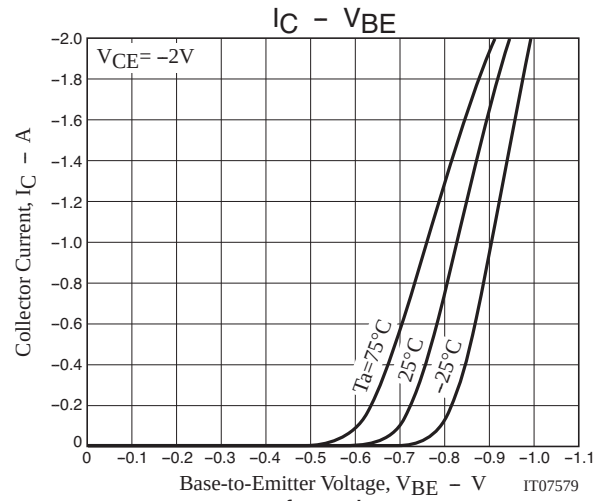
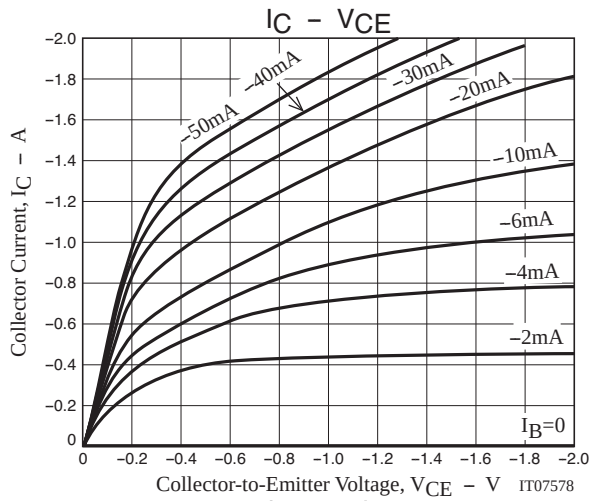
Switching Time Test Circuit

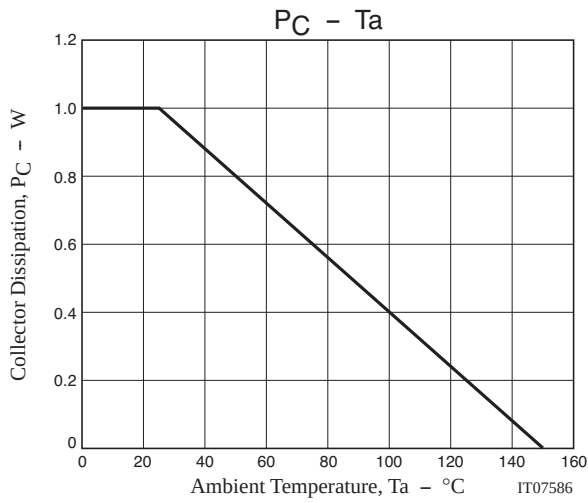


$$I_C = 10I_{B1} = -10I_{B2} = -0.5\text{A}$$

Ordering Information

Device	Package	Shipping	memo
2SA2127	MP	500pcs./bag	Pb Free
2SA2127-AE	MP	1,000pcs./box	





Taping Specification

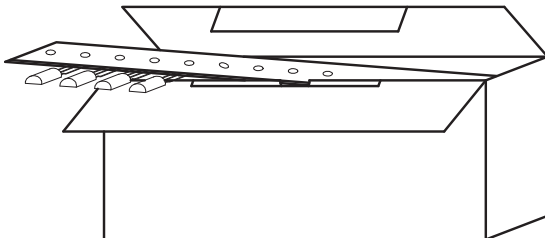
2SA2127-AE

1. Packing Format

Package Name	Packing Type	Maximum Number of devices contained (pcs)		Packing format	
		Inner BOX	number of contained	Outer Box (C-14)	Outer Box (C-15)
M P	AE/AZ	C-3 Dimensions:mm (external) 330×45×125	1,000	16inner Box contained (16,000pcs) Dimensions:mm (external) 500×345×195	8inner Box contained (8,000pcs) Dimensions:mm (external) 345×260×195
	A J	C-5 Dimensions:mm (external) 330×45×245	2,000	8inner Box contained (16,000pcs) Dimensions:mm (external) 500×345×195	4inner Box contained (8,000pcs) Dimensions:mm (external) 345×260×195

Packing method

Put zigzag folding in an inner box.



Inner box label

(unit:mm)

Type No. →

Lot No. →

Quantity →

Origin →

69		43
(P) TYPE	000000000	
(17) LOT	00	
(Q) QTY	0,000 (1) LEAD FREE #	
(2) SPECIAL	*Z0722005310C*	
ASSEMBLY:**** (DIFFUSION:****)		

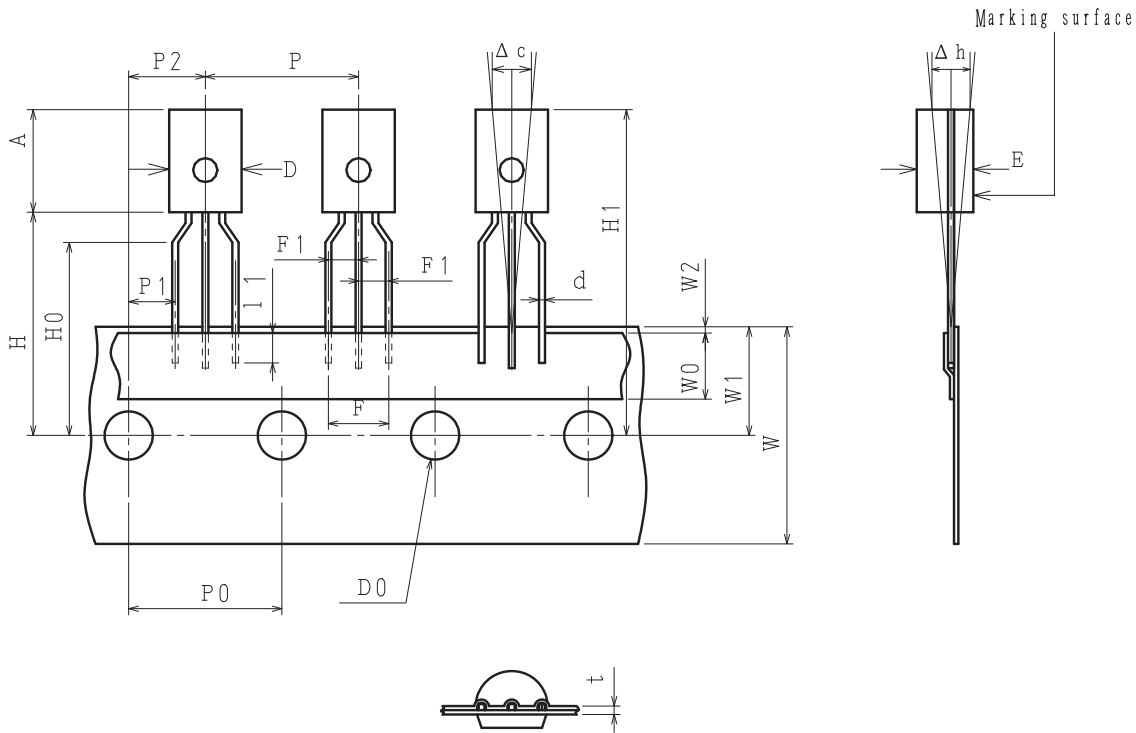
NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping specifications

2-1. Carrier tape size



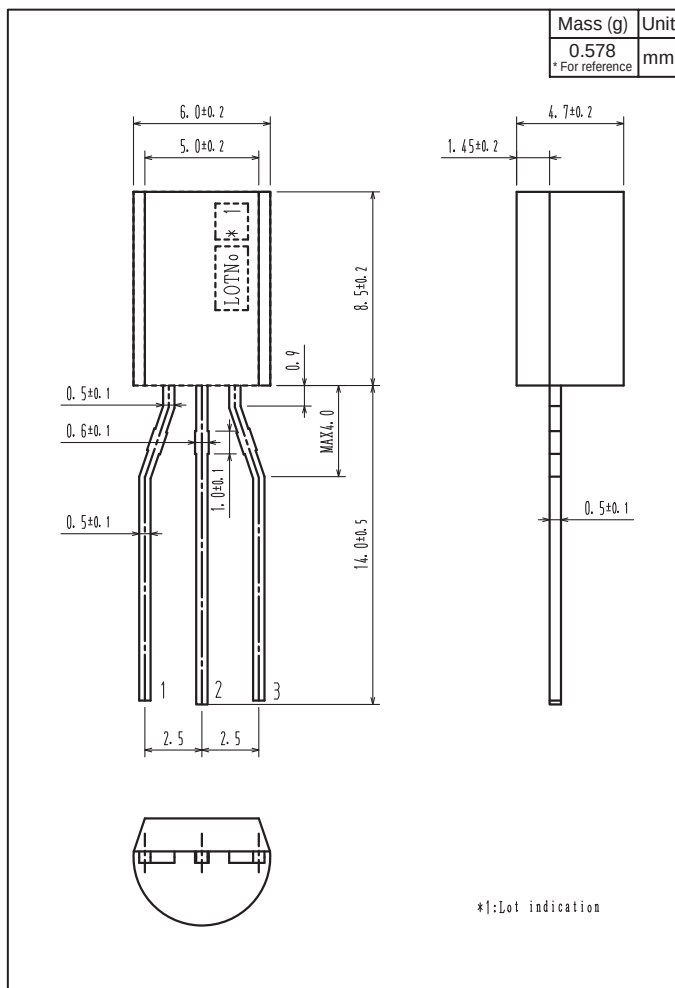
2-2. Taping size standard

unit:mm

Item	Symbol	Standard	Tolerance	Item	Symbol	Standard	Tolerance
Work piece outside diameter	D	6.0	±0.2	Tape width	W	18.0	+1.0 -0.5
	E	4.7	±0.2	Adhesive tape	W0	6.0	±1.5
Work piece height	A	8.5	±0.2	Displacement of perforations	W1	9.0	±0.5
Lead wire diameter	d	0.5×0.5t	±0.1	Work piece bottom surface position	H	18.5	±1.0
Bonded lead wire	l1	2.5MIN		Insert stopper position	H0	16.0	±0.5
Pitch between products	P	12.7	±1.0	Work piece upper limit position	H1	27.0	±1.5
Pitch between perforations	P0	12.7	±0.2	Perforations diameter	D0	φ4.0	±0.2
Accumulation Pitch	P0×20	254.0	±1.0	Tape thickness	t	0.7	±0.2
Distance between lead wire	F	5.0	+0.8 -0.2	Product inclination	Δc	0	±1.5
Lead wire pitch distance	F1	2.5	+0.4 -0.1				
Product inclination	Δh	0	±2.0				
Displacement of perforations	P1	3.85	±0.3	Measurement position is the bottom of the clinch			
	P2	6.35	±0.3				
Displacement of tape	W2	0.5MAX		Not to be displaced to the outside of the board			

Outline Drawing

2SA2127-AE



Bag Packing Specification

2SA2127

1 . Packing condition

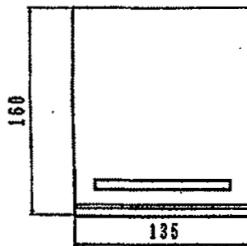
Storage package outline name	Maximum number of devices contained (pcs.)			Packing condition	
	Bags	Inner box	Devices contained	Outer box (A-1)	Outer box (A-2)
MP	500	B-1 inner box dimensions : mm (external) 445×225×55	5,000	5 inner boxes contained (25,000) Outer box dimensions : mm (external) 470 × 250 × 300	3 inner boxes contained (15,000) Outer box dimensions : mm (external) 470 × 250 × 190

3. Bar code label

(Unit : mm)

2. Bag dimensions

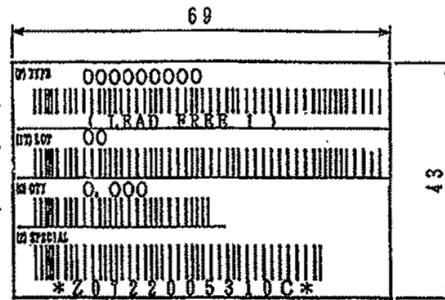
(Unit : mm)



Type No. →

Lot No. →

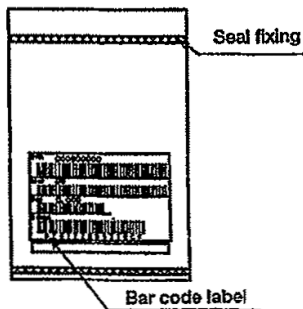
Quantity →



*LEAD FREE 1:

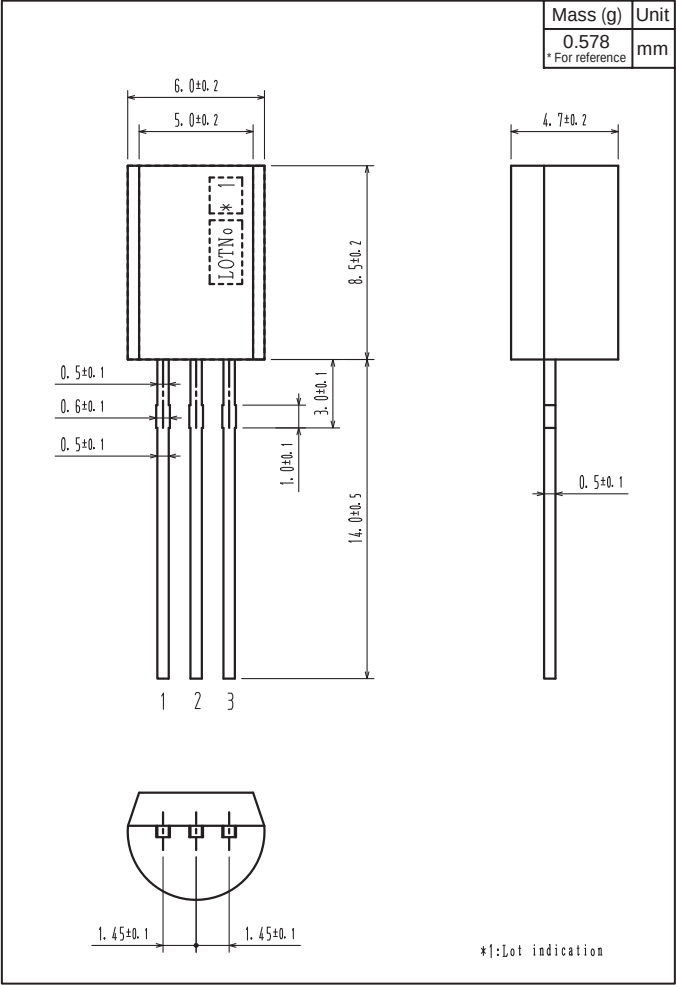
Lead-free External terminal surface
treatment product.

4. Housing devices in the bag



Outline Drawing

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